



1D/2D MIXED NANOCOMPOSITE THIN FILM of SnO₂/CARBON NANOTUBE/GRAPHENE

Z. Rezaei¹, H. Abdizadeh^{*1,2}, M.R. Golobostanfard^{*1}

¹School of Metallurgy and Materials Engineering, College of Engineering, University of Tehran, Tehran, Iran;

²Center of Excellence in Materials for Low-Energy Consumption Technologies, University of Tehran, Tehran, Iran.

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*Corresponding author email: abdizade@ut.ac.ir, bostanfr@ut.ac.ir

ABSTRACT

Tin oxide (SnO₂) has gained much attention in various fields such as optoelectronic industries and gas sensors. SnO₂ thin films have been extensively used as electron transport layers (ETL) in planar perovskite solar cells due to their high stability, good processability, and appropriate band alignment. However, it suffers from relatively low charge mobility. Although there were some successful attempts to improve the charge mobility of SnO₂ thin films by incorporating carbon nanotubes (CNT) or graphene in its structure, the simultaneous addition of these 1D/2D mixed nanostructures in SnO₂, which can lead to far better optoelectronic properties, has never been reported. 1D/2D mixed nanocomposite thin films based on SnO₂/CNT/graphene are successfully synthesized in this research, and the structural, morphological, and optoelectrical properties of the films are investigated. For this purpose, SnO₂ sols were prepared by dissolving and refluxing SnCl₂·2H₂O in 1-propanol at 87 °C for 2 h. In order to synthesize nanocomposite samples, various amounts of CNT and/or graphene were added to the solution prior to refluxing. The films were deposited by dip coating and subsequently calcined at 180 °C. The thin films were studied using X-ray diffraction (XRD), field emission scanning electron microscopy (FESEM), and UV-Vis spectroscopy. The XRD results confirm the formation of the SnO₂ phase. FESEM images thoroughly demonstrate the presence of CNTs and graphene beside SnO₂ nanoparticles. The absorbance of the films as well as their band gaps remained almost constant after CNT/graphene addition.

Keywords: Thin layers; Nanocomposites; Graphene; Carbon nanotubes; Tin oxide; Sol-gel.

1. Introduction

Metal oxide semiconductor nanomaterials present themselves in various areas of science and technology due to their unique physical and chemical properties [1]. Among various metal oxide nanomaterials, SnO₂ has become the foremost one because of its wide applications in lithium batteries, supercapacitors, gas sensors, catalysis, and electron transport layers (ETL) in planar perovskite solar cells (PSCs) [2,3]. However, pure tin oxide shows relatively low charge mobility, and planar devices based on pure solution-processed SnO₂ ETL still

have hysteresis, which significantly limits the application of SnO₂ in high-efficiency solar cells [4].

By means of addressing this issue, Tang et al. [5] fabricated a hybrid ETL of SnO₂ and carbon nanotube. The addition of CNTs can significantly improve the conductivity of SnO₂ films and reduce the trap-state density of SnO₂ films, which benefit carrier transfer from the perovskite layer to the cathode [5]. As it is reported, the hysteresis-free PSCs based on SnO₂-CNT ETL show higher efficiency than the conventional device [5].

The addition of graphene is another reported approach. Graphene and its nanocomposites with different semiconductor materials have attracted significant research attention in the last decade due to their improved performance in various fields [6]. Adding graphene to SnO₂ increases carrier mobility, indicating that rGO-SnO₂ has better charge transport due to enhanced electron-hole separation attributed to graphene [7].

It is a surmise that the addition of the CNT/graphene to SnO₂ can improve its optoelectronic properties. Thus, a novel 1D/2D mixed nanocomposite thin film of SnO₂/CNT/Graphene has been represented in this study.

2. Experimental details

SnO₂/CNT/Graphene films were prepared by the sol-gel method and coated through the dip-coating process. MWCNT-10 (95%) with a length of 1 μm and diameter of 10 nm was purchased from Shezen NanoTech Co. Graphene oxide (99%) with a layer number of 6-10 and area of 1 μm² was purchased from US Research Nanomaterials Co. (US-Nano). SnCl₂·2H₂O, 1-propanol, nitric acid, and sulfuric acid (Sigma-Aldrich Co.) were analytical-grade reagents and were used as purchased without further purification. By synthesizing SnO₂/CNT/Graphene nanocomposite, CNTs were first functionalized by adding a 0.05 g CNT to a solution containing nitric acid and sulfuric acid with a 1:3 dilution ratio at 80 °C for one hour. The mixture was collected by centrifugation, washed with distilled water, and dried at 100 °C.

In the second step, SnCl₂·2H₂O was dissolved in

1-propanol to reach a 0.1 M solution. Meanwhile, 0.0006 g of pre-treated MWCNTs and 0.0006 g of Graphene oxide were dispersed in another portion of 1-propanol (10 ml) separately by an ultrasonic bath. In the third step, SnCl₂·2H₂O solution (9 ml), graphene oxide, and MWCNT suspensions (0.5 ml of each) were mixed and refluxed at 87 °C for 2 h. The final product was coated on standard glass slides through the dip-coating process, then, calcined at 180 °C. For comparison, films of bare SnO₂, SnO₂/CNT, and SnO₂/graphene were prepared according to the above procedure.

The morphologies, crystal phases, and absorbance of the as-prepared films are investigated by field emission scanning electron microscope (FESEM; MIRA3; TESCAN co.), X-ray diffraction (XRD; Xpertpro Philips; 40 kV, 30 mA, Cu-ka radiation), and UV-Vis spectrophotometer (Photonix Ar 2015; 230 V ± 5%, 50 Hz, 85 W).

3. Results and discussion

Fig. 1 presents FESEM images of (a-1, a-2) bare SnO₂, (b-1, b-2) SnO₂/CNT, (c-1, c-2, c-3) SnO₂/graphene, and (d-1, d-2) SnO₂/CNT/graphene films synthesized through the sol-gel method and calcined at 180 °C at different magnifications. It can be illustrated that the addition of functionalized CNT and/or graphene to the primary sol controls the cubic SnO₂ particles' nucleation and the final size of SnO₂ particles reduces. Although the proportion of CNT and graphene is low (1%wt), figures 1(b-d) show a good distribution and dispersion of CNT and graphene in the prepared nanocomposites.

Fig. 1b shows that CNTs present within the

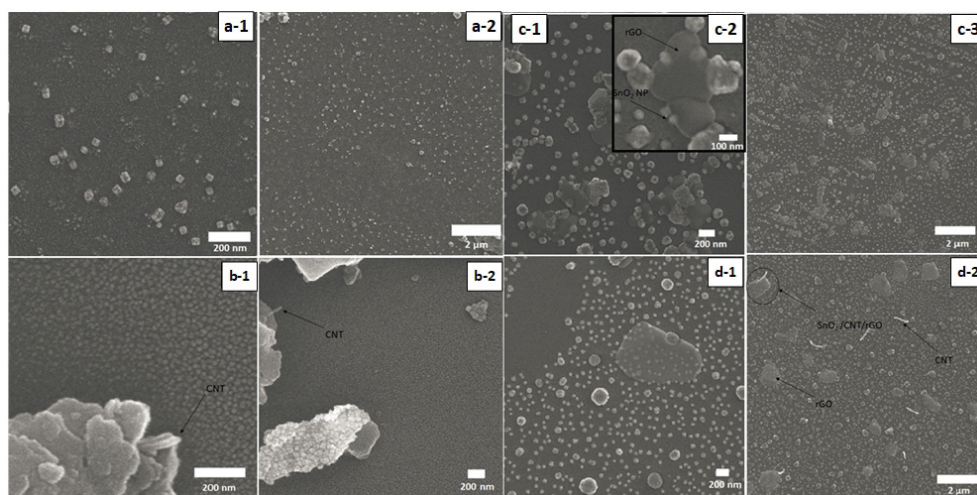


Fig. 1- FESEM images of (a) bare SnO₂, (b) SnO₂/CNT nanocomposite, (c) SnO₂/graphene nanocomposite, (d) SnO₂/CNT/graphene nanocomposite.

agglomerated SnO₂ and in Fig. 1c, the presence of tiny SnO₂ nanoparticles uniformly distributed on the graphene sheets is clearly observed. In Fig. 1d light lines, wide transparent sheets, and spherical particles attribute to CNT, graphene, and SnO₂ nanoparticles, respectively, which proves the formation of SnO₂/CNT/graphene nanocomposite.

Fig. 2 shows the XRD patterns of SnO₂ after being calcined at 500 °C (a) and SnO₂/CNT/graphene nanocomposite after being calcined at 180 °C (b) for 1h. In both Fig. 2a and 2b, SnO₂ diffraction peaks are identified according to JCPDS card no. 7534-900-96. In Fig. 2b, broad XRD peaks with low intensity are visible indicating that the

crystallization of SnO₂ nanoparticles was initiated. In addition, it is noticeable that the broad XRD peaks indicate a much smaller crystal size for SnO₂ nanoparticles. The poor signal-to-noise ratio may be due to the poor crystallinity of the SnO₂ nanoparticles. Due to the low proportion of CNT and graphene (1%wt) and the overlap of their XRD pattern with SnO₂, no separate CNT and graphene characteristic diffraction peaks are observed.

Fig. 3 presents a comparison between UV-Visible spectra of bare SnO₂, SnO₂/CNT, SnO₂/graphene, and SnO₂/CNT/graphene nanocomposite films. As it is shown in the UV-vis spectra and tauc's plots of samples, the band gap (3.598 eV) and absorbance of

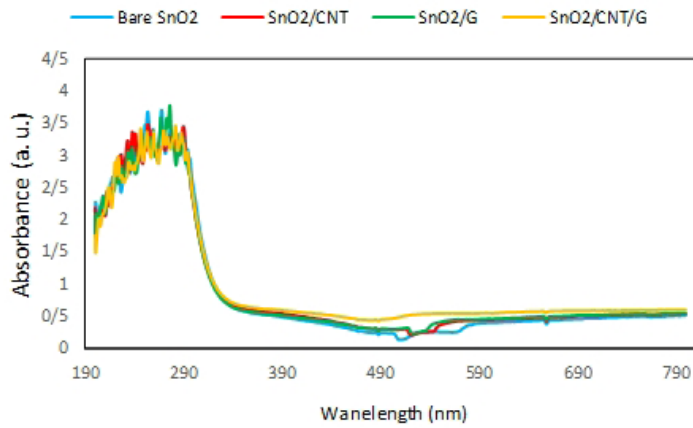


Fig. 2- XRD patterns of bare SnO₂ after being calcined at 500 °C (a) and SnO₂/CNT/graphene nanocomposite after being calcined at 180 °C (b).

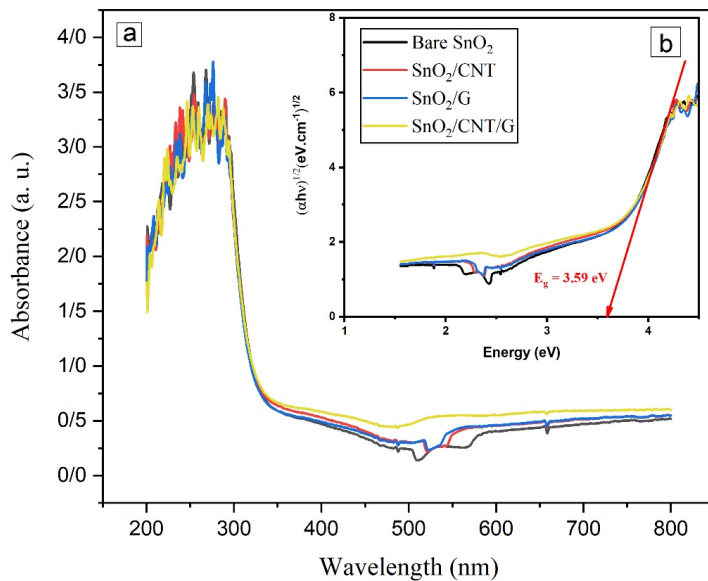


Fig. 3- (a) UV-Visible spectra and (b) The Tauc's plot of bare SnO₂, SnO₂/CNT, SnO₂/graphene, and SnO₂/CNT/graphene nanocomposite films.

the films after the addition of CNT and graphene has been remained constant due to the low proportion of CNT and graphene. Moreover, the transmittance of the films does not change dramatically by CNT/graphene addition.

4. Conclusions

In summary, in the present work, SnO₂/CNT/graphene films have been successfully synthesized through the sol-gel method and coated by the dip-coating process. XRD analysis showed the SnO₂ crystal structure initiation for the sample calcined at 500 °C, and a low degree of crystallinity for the sample calcined at 180 °C. Also, it has been observed from FESEM figures that the SnO₂/CNT/graphene nanocomposite was well-formed. To be added, UV-visible spectroscopy results showed that the transparency and bandgap of the films remained constant with CNT/graphene addition. Thus, in this novel study, a hybrid of SnO₂/CNT/graphene nanocomposite film was well synthesized by the sol-gel method.

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